#### **DISCRETE SEMICONDUCTORS**

## DATA SHEET



# **BYX133G**High-voltage car ignition diode

Product specification Supersedes data of 2000 Feb 29

2001 Oct 02





#### High-voltage car ignition diode

**BYX133G** 

#### **FEATURES**

- · Glass passivated
- · High maximum operating temperature
- · Low leakage current
- · Excellent stability
- · Guaranteed avalanche energy absorption capability.

#### **APPLICATIONS**

- · Car ignition systems
- Automotive applications with extreme temperature requirements.

#### **DESCRIPTION**

Rugged glass package, using a high temperature alloyed construction.

The SOD61AB2 is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.

The package is designed to be used in an insulating medium such as resin, oil or SF6 gas.

The BYX133G is marked with a brown cathode band on the body.

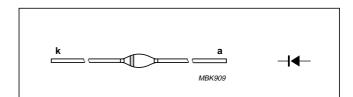


Fig.1 Simplified outline (SOD61AB2) and symbol.

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{RRM}$	repetitive peak reverse voltage		_	3	kV
$V_{RWM}$	crest working reverse voltage		_	3	kV
I <sub>F(AV)</sub>	average forward current		_	50	mA
I <sub>FRM</sub>	repetitive peak forward current		_	500	mA
I <sub>RSM</sub>	non-repetitive peak reverse current	t = 100 μs triangular pulse; T <sub>j max</sub> prior to surge	_	50	mA
T <sub>stg</sub>	storage temperature		-65	+200	°C
Tj	junction temperature	continuous	_	175	°C
Tį	junction temperature	max. 30 min.	_	200	°C

#### **CHARACTERISTICS**

T<sub>i</sub> = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 10 mA	3.75	5.25	V
V <sub>(BR)R</sub>	reverse avalanche breakdown voltage	I <sub>R</sub> = 100 μA	4	5.5	kV
I <sub>R</sub>	reverse current	$V_R = V_{RWMmax}$ ; $T_j = 175  ^{\circ}C$	_	30	μΑ

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	$T_{amb} = T_{leads}$ ; lead length = 10 mm	90	K/W

## High-voltage car ignition diode

BYX133G

#### **GRAPHICAL DATA**

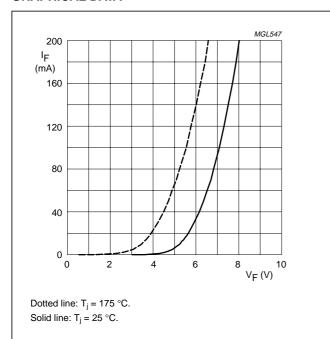


Fig.2 Forward current as a function of maximum forward voltage.

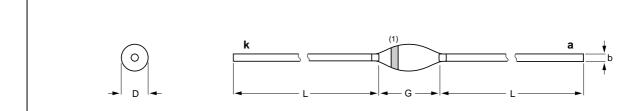
### High-voltage car ignition diode

BYX133G

#### **PACKAGE OUTLINE**

Hermetically sealed glass package; axial leaded; 2 leads

SOD61AB2



#### **DIMENSIONS** (mm are the original dimensions)

UNIT	b	D max.	G max.	L min.
mm	0.6	2.5	5.5	31.8

0 2.5 5 mm scale

#### Note

1. The marking band indicates the cathode.

OUTLINE	OUTLINE REFERENCES		EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1330E DATE
SOD61AB2						98-12-04

#### High-voltage car ignition diode

BYX133G

#### **DATA SHEET STATUS**

DATA SHEET STATUS(1)	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification.  Supplementary data will be published at a later date. Philips  Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

#### **Notes**

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

#### **DEFINITIONS**

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

#### **DISCLAIMERS**

Life support applications — These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no licence or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

## High-voltage car ignition diode

BYX133G

NOTES

## High-voltage car ignition diode

BYX133G

NOTES

## Philips Semiconductors – a worldwide company

#### **Contact information**

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

© Koninklijke Philips Electronics N.V. 2001

SCA73

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Printed in The Netherlands

613510/04/pp8

Date of release: 2001 Oct 02

Document order number: 9397 750 08881

Let's make things better.





